

Supplementary Pages

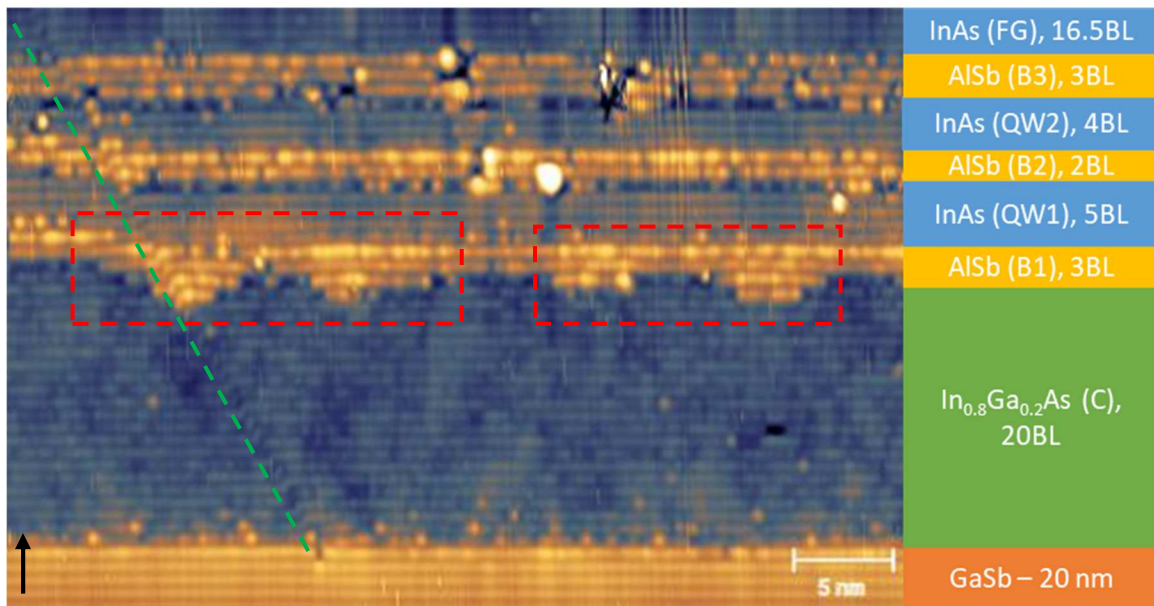


Figure 1. 40×35 nm filled state topography image of the TBRT structure, the InGaAs layer and the GaSb layer ($V_b = -3$ V and $I_t = 50$ pA). The QPs and the slip plane are highlighted by the dashed red rectangles and the dashed green line, respectively. The arrow indicates the growth direction. BL: atomic bilayers, i.e. lattice constants.